

Precision Low Power FGA™ Voltage References

ISL60002

The ISL60002 FGA™ voltage references are very high precision analog voltage references fabricated in Intersil's proprietary Floating Gate Analog technology and feature low supply voltage operation at ultra-low 350nA operating current.

Additionally, the ISL60002 family features guaranteed initial accuracy as low as $\pm 1.0 mV$ and $20 ppm/\,^{\circ}C$ temperature coefficient. The initial accuracy and temperature stability performance of the ISL60002 family, plus the low supply voltage and 350nA power consumption, eliminates the need to compromise thermal stability for reduced power consumption making it an ideal companion to high resolution, low power data conversion systems.

Special Note: Post-assembly x-ray inspection may lead to permanent changes in device output voltage and should be minimized or avoided. For further information, please see "Applications Information" on page 34 and AN1533, "X-Ray Effects on Intersil FGA References".

Applications

- · High resolution A/Ds and D/As
- · Digital meters
- · Bar code scanners
- Mobile communications
- · PDA's and notebooks
- · Medical systems

Features

- Reference voltages 1.024V, 1.2V, 1.25V, 1.8V, 2.048V, 2.5V, 2.6V, 3.0V and 3.3V
- Absolute initial accuracy options ±1.0mV, ±2.5mV and ±5.0mV
- · Supply voltage range

-	ISL60002-10, -11, -12, -18, -20, -25	2.7V to	5.57
-	ISL60002-26	2.8V to	5.5V
-	ISL60002-30	3.2V to	5.5V
-	ISL60002-33	3.5V to	5.5V

- Ultra-low supply current......350nA typ
- Low 20ppm/°C temperature coefficient
- I_{SOURCE} and I_{SINK} = 7mA
- I_{SOURCE} and I_{SINK} = 20mA for ISL60002-33 only
- ESD protection 5500V (human body model)
- · Standard 3 Ld SOT-23 packaging
- · Operating temperature range
 - ISL60002-10, -11, -12, -18, -20, -25, -26, -30-40°C to +85°C
 - ISL60002-33-40°C to +105°C
- Pb-Free (RoHS Compliant)

Related Literature

- See <u>AN1494</u>, "Reflow and PC Board Assembly Effects on Intersil FGA References"
- See AN1533, "X-Ray Effects on Intersil FGA References"
- See <u>TB475</u>, "ISL21009-25 and ISL60002-30 Capacitive Load Drive Capability"
- See AN1843 "ISL60002XXEVAL1Z User's Guide"

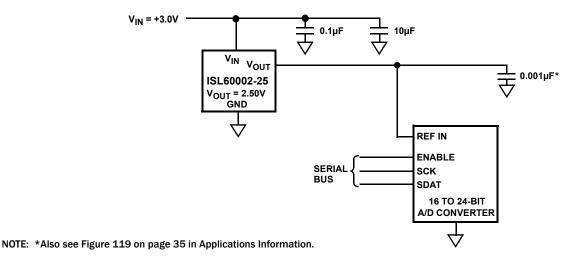


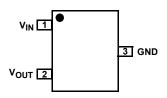
FIGURE 1. TYPICAL APPLICATION

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Pin Configuration

ISL60002 (3 LD SOT-23) TOP VIEW



Pin Descriptions

PIN NUMBER	PIN NAME	DESCRIPTION
1	V _{IN}	Power Supply Input
2	V _{OUT}	Voltage Reference Output
3	GND	Ground

Ordering Information

PART NUMBER (Notes 1, 2, 3)	PART MARKING	V _{OUT} (V)	GRADE	TEMP. RANGE (°C)	PACKAGE (Pb-free)	PKG. DWG.#
ISL60002BIH320Z	DEY (Note 4)	2.048	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH325Z	AON (Note 4)	2.500	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH320Z	DEZ (Note 4)	2.048	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DAH333Z	APC (Note 4)	3.300	±5.0mV, 20ppm/°C	-40 to +105	3 Ld SOT-23	P3.064
ISL60002BIH310Z-TK	DFB (Note 4)	1.024	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH310Z-TK	DFC (Note 4)	1.024	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH310Z-TK	DFD (Note 4)	1.024	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH311Z-TK	APM (Note 4)	1.200	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH311Z-TK	AOR (Note 4)	1.200	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH311Z-TK	AOY (Note 4)	1.200	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH312Z-TK	AOM (Note 4)	1.250	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH312Z-TK	AOS (Note 4)	1.250	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH312Z-TK	APA (Note 4)	1.250	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH318Z-TK	DEO (Note 4)	1.800	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH318Z-TK	DEP(Note 4)	1.800	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH318Z-TK	DEQ (Note 4)	1.800	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH320Z-TK	DEY (Note 4)	2.048	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH320Z-TK	DEZ (Note 4)	2.048	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH320Z-TK	DFA (Note 4)	2.048	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH325Z-TK	AON (Note 4)	2.500	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH325Z-TK	APB (Note 4)	2.500	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH325Z-TK	AOT (Note 4)	2.500	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH326Z-TK	DFK (Note 4)	2.600	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH326Z-TK	DFL (Note 4)	2.600	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH326Z-TK	DFM (Note 4)	2.600	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH330Z-TK	DFI (Note 4)	3.000	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH330Z-TK	DFJ (Note 4)	3.000	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH330Z-TK	DFH (Note 4)	3.000	±5.0mV, 20ppm/°C	-40 to +85	3 Ld S0T-23	P3.064
ISL60002BAH333Z-TK	AOP (Note 4)	3.300	±1.0mV, 20ppm/°C	-40 to +105	3 Ld S0T-23	P3.064
ISL60002CAH333Z-TK	AOU (Note 4)	3.300	±2.5mV, 20ppm/°C	-40 to +105	3 Ld SOT-23	P3.064

Ordering Information (Continued)

PART NUMBER (Notes 1, 2, 3)	PART MARKING	V _{OUT} (V)	GRADE	TEMP. RANGE (°C)	PACKAGE (Pb-free)	PKG. DWG. #
ISL60002DAH333Z-TK	APC (Note 4)	3.300	±5.0mV, 20ppm/°C	-40 to +105	3 Ld SOT-23	P3.064
ISL60002BAH333Z-T7A	AOP (Note 4)	3.300	±1.0mV, 20ppm/°C	-40 to +105	3 Ld SOT-23	P3.064
ISL60002BIH310Z-T7A	DFB (Note 4)	1.024	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH320Z-T7A	DEY (Note 4)	2.048	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002BIH325Z-T7A	AON (Note 4)	2.500	±1.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002CIH325Z-T7A	AOT (Note 4)	2.500	±2.5mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DAH333Z-T7A	APC (Note 4)	3.300	±5.0mV, 20ppm/°C	-40 to +105	3 Ld SOT-23	P3.064
ISL60002DIH310Z-T7A	DFD (Note 4)	1.024	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH312Z-T7A	APA (Note 4)	1.250	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH325Z-T7A	APB (Note 4)	2.500	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064
ISL60002DIH330Z-T7A	DFH (Note 4)	3.000	±5.0mV, 20ppm/°C	-40 to +85	3 Ld SOT-23	P3.064

NOTES:

- 1. Please refer to TB347 for details on reel specifications.
- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. For Moisture Sensitivity Level (MSL), please see device information page for ISL60002. For more information on MSL please see techbrief TB363.
- 4. The part marking is located on the bottom of the part.

Absolute Maximum Ratings

Max Voltage V _{IN} to GND	0.5V to +6.5V
Max Voltage V _{OUT} to GND (10s):	0.5V to +V _{OUT} + 1V
Voltage on "DNC" pins No connec	tions permitted to these pins
ESD Ratings	
Human Body Model	5500V
Machine Model	550V

Charged Device Model

Environmental Operating Conditions

X-Ray Exposure (Note 5)	 10mRem

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
3 Ld SOT-23 (Notes 6, 7)	275	110
Continuous Power Dissipation (T _A = +85 °C)		99mW
Maximum Junction Temperature (Plastic Pac	kage)	+107°C
Storage Temperature Range	6	5°C to +150°C
Pb-Free Reflow Profile		see link below
http://www.intersil.com/pbfree/Pb-FreeR	eflow.asp	

Recommended Operating Conditions

Temperature Range	
Industrial	40°C to +85°C
3.3V Version	40°C to +105°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES

- 5. Measured with no filtering, distance of 10" from source, intensity set to 55kV and 70mA current, 30s duration. Other exposure levels should be analyzed for Output Voltage drift effects. See "Applications Information" on page 34.
- 6. θ_{IA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 7. For $\theta_{\mbox{\scriptsize JC}},$ the "case temp" location is taken at the package top center.
- 8. Post-reflow drift for the ISL60002 devices will range from 100μV to 1.0mV based on experimental results with devices on FR4 double sided boards. The design engineer must take this into account when considering the reference voltage after assembly.
- 9. Post-assembly x-ray inspection may also lead to permanent changes in device output voltage and should be minimized or avoided. Initial accuracy can change 10mV or more under extreme radiation. Most inspection equipment will not affect the FGA reference voltage, but if x-ray inspection is required, it is advisable to monitor the reference output voltage to verify excessive shift has not occurred.

Electrical Specifications ISL60002-10, $V_{OUT} = 1.024V$ (Additional specifications on page 9, "Common Electrical Specifications") Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0mA$, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +85°C

			MIN (Note		MAX (Note	
SYMBOL	PARAMETER	CONDITIONS	10)	TYP	10)	UNITS
V _{OUT}	Output Voltage			1.024		V
V _{OA}	NOTES:V _{OUT} Accuracy (Notes 11, 9)	T _A = +25°C				
		ISL60002B10	-1.0		+1.0	mV
		ISL60002C10	-2.5		+2.5	mV
		ISL60002D10	-5.0		+5.0	mV
V _{IN}	Input Voltage Range		2.7		5.5	V

Electrical Specifications ISL60002-11, V_{OUT} = 1.200V (Additional specifications on page 9, "Common Electrical Specifications"). Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0$ mA, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40**°C to +85°C

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	ТҮР	MAX (Note 10)	UNITS
v _{out}	Output Voltage			1.200		٧
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C ISL60002B11 ISL60002C11 ISL60002D11	-1.0 -2.5 -5.0		+1.0 +2.5 +5.0	mV mV
V _{IN}	Input Voltage Range	i3L0000ZDII	2.7		5.5	V

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Electrical Specifications ISL60002-12, V_{OUT} = 1.250V (Additional specifications on page 9, "Common Electrical Specifications") Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0$ mA, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40**°C to +85°C

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			1.250		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C ISL60002B12 ISL60002C12 ISL60002D12	-1.0 -2.5 -5.0		+1.0 +2.5 +5.0	mV mV mV
V _{IN}	Input Voltage Range		2.7		5. 5	V

Electrical Specifications ISL60002-18, V_{OUT} = 1.800V (Additional specifications on page 9, "Common Electrical Specifications"). Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0mA$, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40**°C to +85°C

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			1.800		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C ISL60002B18 ISL60002C18 ISL60002D18	-1.0 -2.5 -5.0		+1.0 +2.5 +5.0	mV mV mV
V _{IN}	Input Voltage Range		2.7		5.5	V

Electrical Specifications ISL60002-20, V_{OUT} = 2.048V (Additional specifications on page 9, "Common Electrical Specifications"). Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0mA$, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40**°C to +85°C

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			2.048		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C ISL60002B20	-1.0		+1.0	mV
		ISL60002C20	-2.5		+2.5	mV
		ISL60002D20	-5.0		+5.0	mV
V _{IN}	Input Voltage Range		2.7		5.5	V

Electrical Specifications ISL60002-25, V_{OUT} = 2.500V (Additional specifications on page 9, "Common Electrical Specifications"). Operating Conditions: V_{IN} = 3.0V, I_{OUT} = 0mA, C_{OUT} = 0.001 μ F, T_A = -40 to +85 °C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40 °C to +85 °C**

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			2.500		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C ISL60002B25 ISL60002C25 ISL60002D25	-1.0 -2.5 -5.0		+1.0 +2.5 +5.0	mV mV
V _{IN}	Input Voltage Range	ISL00002D23	2.7		5.5	V

Electrical Specifications ISL60002-26, V_{OUT} = 2.600V (Additional specifications on page 9, "Common Electrical Specifications"). Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0$ mA, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40°C to +85°C**

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
v _{out}	Output Voltage			2.600		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C				
		ISL60002B26	-1.0		+1.0	mV
		ISL60002C26	-2.5		+2.5	mV
		ISL60002D26	-5.0		+5.0	mV
V _{IN}	Input Voltage Range		2.8		5.5	V
TC V _{OUT}	Output Voltage Temperature Coefficient (Note 11)				20	ppm/°C
I _{IN}	Supply Current			350	900	nA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$+2.8V \le V_{IN} \le +5.5V$		80	350	μV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	0mA ≤ I _{SOURCE} ≤ 7mA		25	100	μV/mA
		-7mA ≤ I _{SINK} ≤ 0mA		50	250	μV/mA
$\Delta V_{OUT}/\Delta T_{A}$	Thermal Hysteresis (Note 12)	$\Delta T_A = +125$ °C		100		ppm
$\Delta V_{OUT}/\Delta t$	Long Term Stability (Note 13)	T _A = +25°C; First 1khrs		50		ppm
I _{SC}	Short Circuit Current (to GND)*	T _A = +25°C		50		mA
V _N	Output Voltage Noise	$0.1 Hz \le f \le 10 Hz$		30		μV _{P-P}

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			3.000		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C				
		ISL60002B30	-1.0		+1.0	mV
		ISL60002C30	-2.5		+2.5	m۷
		ISL60002D30	-5.0		+5.0	mV
V _{IN}	Input Voltage Range		3.2		5.5	٧
TC V _{OUT}	Output Voltage Temperature Coefficient (Note 11)				20	ppm/°C
I _{IN}	Supply Current			350	900	nA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$+3.2V \le V_{1N} \le +5.5V$		80	250	μV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	$0mA \leq I_{\mbox{SOURCE}} \leq 7mA$		25	100	μV/mA
		-7mA ≤ I _{SINK} ≤ 0mA		50	150	μV/mA
$\Delta V_{OUT}/\Delta T_{A}$	Thermal Hysteresis (Note 12)	ΔT _A = +125°C		100		ppm
$\Delta V_{OUT}/\Delta t$	Long Term Stability (Note 13)	T _A = +25°C; First 1khrs		50		ppm
I _{SC}	Short Circuit Current (to GND)	T _A = +25°C		50		mA
V _N	Output Voltage Noise	$0.1 Hz \leq f \leq 10 Hz$		30		μV _{P-P}

Electrical Specifications ISL60002-33, V_{OUT} = 3.300V operating Conditions: V_{IN} = 5.0V, I_{OUT} = 0mA, C_{OUT} = 0.001 μ F, T_A = -40 to +105°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40°C to +105°C**

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
V _{OUT}	Output Voltage			3.300		V
V _{OA}	V _{OUT} Accuracy (Note 11)	T _A = +25°C				
		ISL60002B33	-1.0		1.0	mV
		ISL60002C33	-2.5		2.5	mV
		ISL60002D33	-5.0		5.0	mV
TC V _{OUT}	Output Voltage Temperature Coefficient (Note 11)				20	ppm/°C
V _{IN}	Input Voltage Range		3.5		5.5	V
I _{IN}	Supply Current			350	700	nA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	+3.5V ≤ V _{IN} ≤ +5.5V		80	200	μV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	0mA ≤ I _{SOURCE} ≤ 20mA		25	100	μV/mA
		-20mA ≤ I _{SINK} ≤ 0mA		50	150	μV/mA
$\Delta V_{OUT}/\Delta T_{A}$	Thermal Hysteresis (Note 12)	$\Delta T_A = +145$ °C		100		ppm
$\Delta V_{OUT}/\Delta t$	Long Term Stability (Note 13)	T _A = +25°C; First 1khrs		50		ppm
I _{SC}	Short Circuit Current (to GND)	T _A = +25°C		50		mA
V_N	Output Voltage Noise	$0.1 Hz \le f \le 10 Hz$		30		μV _{P-P}

Common Electrical Specifications ISL60002 -10, -11, -12, -18, -20, and -25

Operating Conditions: $V_{IN} = 3.0V$, $I_{OUT} = 0mA$, $C_{OUT} = 0.001\mu$ F, $T_A = -40$ to +85°C, unless otherwise specified. **Boldface limits apply over the operating temperature range, -40**°C to +85°C

SYMBOL	PARAMETER	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNITS
TC V _{OUT}	Output Voltage Temperature Coefficient (Note 11)				20	ppm/°C
I _{IN}	Supply Current			350	900	nA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$+2.7V \le V_{1N} \le +5.5V$		80	250	μV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	$0mA \leq I_{\mbox{SOURCE}} \leq 7mA$		25	100	μV/mA
		-7mA ≤ I _{SINK} ≤ 0mA		50	150	μV/mA
$\Delta V_{OUT}/\Delta T_{A}$	Thermal Hysteresis (Note 12)	ΔT _A = +125°C		100		ppm
$\Delta V_{OUT}/\Delta t$	Long Term Stability (Note 13)	T _A = +25°C; First 1khrs		50		ppm
Isc	Short Circuit Current (to GND) (Note 14)	T _A = +25°C		50		mA
V _N	Output Voltage Noise	$0.1 Hz \leq f \leq 10 Hz$		30		μV _{P-P}

NOTES:

- 10. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.
- 11. Over the specified temperature range. Temperature coefficient is measured by the box method whereby the change in V_{OUT} is divided by the temperature range: (-40°C to +85°C = +125°C, or -40°C to +105°C = +145°C for the ISL60002-33).
- 12. Thermal Hysteresis is the change in V_{OUT} measured @ T_A = +25°C after temperature cycling over a specified range, ΔT_A , V_{OUT} is read initially at T_A = +25°C for the device under test. The device is temperature cycled and a second V_{OUT} measurement is taken at +25°C. The difference between the initial V_{OUT} reading and the second V_{OUT} reading is then expressed in ppm. For ΔT_A = +125°C, the device under is cycled from +25°C to +85°C to -40°C to +25°C, and for ΔT_A = +145°C, the device under is cycled from +25°C to +105°C to -40°C to +25°C
- 13. Long term drift is logarithmic in nature and diminishes over time. Drift after the first 1000 hours will be approximately 10ppm.
- 14. Short Circuit Current (to V_{CC}) for ISL60002-25 at V_{IN} = 5.0V and +25°C is typically around 30mA. Shorting V_{OUT} to V_{CC} is not recommended due to risk of resetting the part.

Typical Performance Characteristic Curves, V_{OUT} = 1.024V

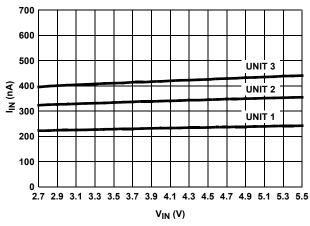


FIGURE 2. I_{IN} vs V_{IN}, 3 UNITS

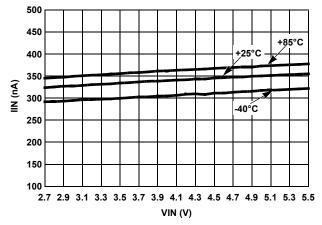


FIGURE 3. I_{IN} vs V_{IN} OVER-TEMPERATURE

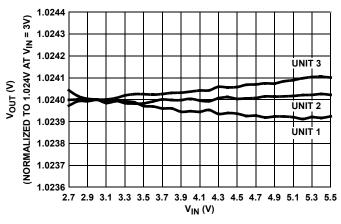


FIGURE 4. LINE REGULATION, 3 UNITS

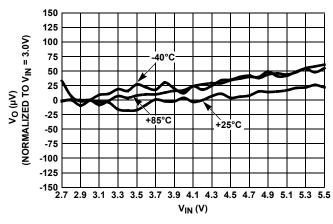


FIGURE 5. LINE REGULATION OVER-TEMPERATURE

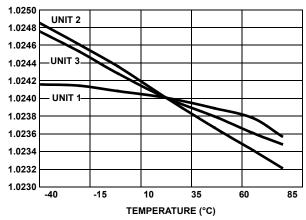
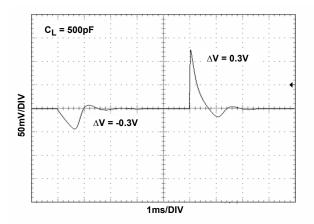


FIGURE 6. V_{OUT} vs TEMPERATURE NORMALIZED to +25°C

Typical Performance Characteristic Curves, V_{OUT} = 1.024V_(Continued)



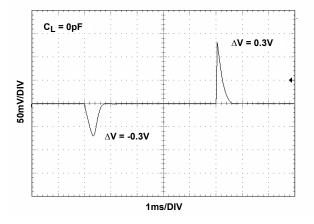


FIGURE 7. LINE TRANSIENT RESPONSE, WITH CAPACITIVE LOAD

FIGURE 8. LINE TRANSIENT RESPONSE

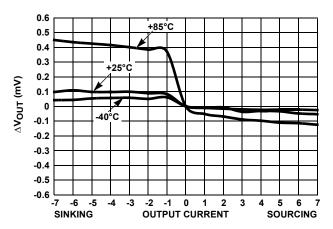


FIGURE 9. LOAD REGULATION OVER-TEMPERATURE

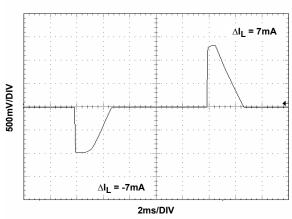


FIGURE 10. LOAD TRANSIENT RESPONSE

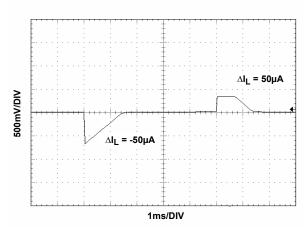


FIGURE 11. LOAD TRANSIENT RESPONSE

Typical Performance Characteristic Curves, V_{OUT} = 1.024V_(Continued)

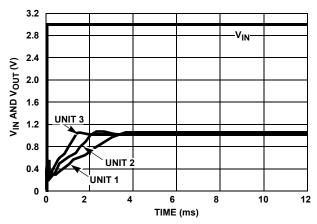


FIGURE 12. TURN-ON TIME (+25°C)

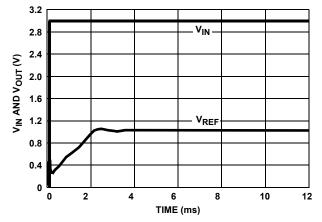


FIGURE 13. TURN-ON TIME (+25°C)

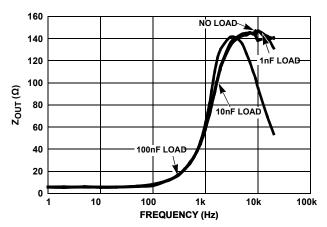


FIGURE 14. Z_{OUT} vs FREQUENCY

Typical Performance Characteristic Curves, V_{OUT} = 1.20V

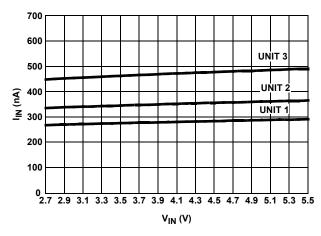


FIGURE 15. I_{IN} vs V_{IN} , 3 UNITS

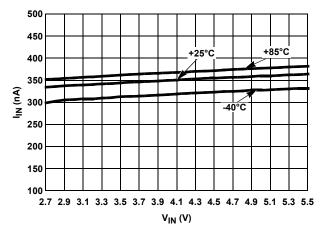


FIGURE 16. I_{IN} vs V_{IN} OVER-TEMPERATURE

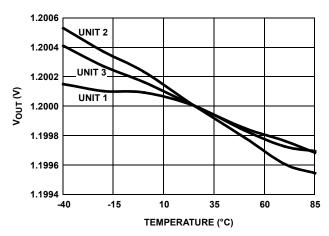


FIGURE 17. V_{OUT} vs TEMPERATURE NORMALIZED TO +25 °C

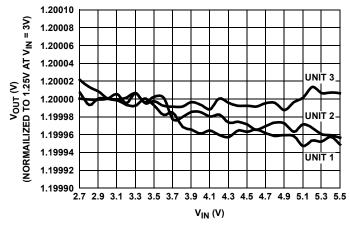


FIGURE 18. LINE REGULATION, 3 UNITS

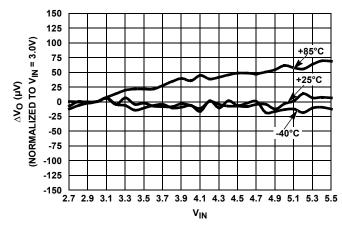


FIGURE 19. LINE REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, V_{OUT} = 1.20V_(Continued)

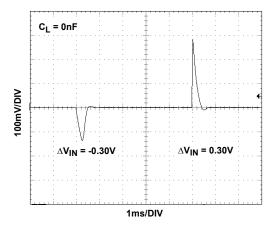


FIGURE 20. LINE TRANSIENT RESPONSE

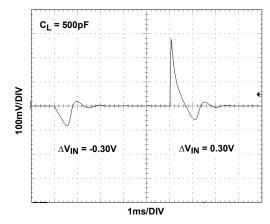


FIGURE 21. LINE TRANSIENT RESPONSE WITH CAPACITIVE LOAD

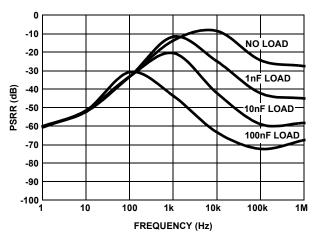


FIGURE 22. PSRR vs CAPACITIVE LOAD

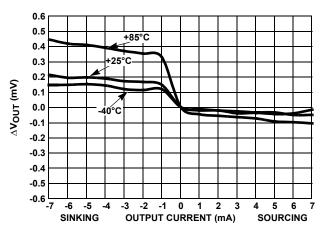


FIGURE 23. LOAD REGULATION OVER-TEMPERATURE

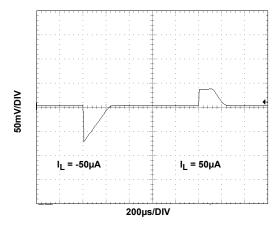


FIGURE 24. LOAD TRANSIENT RESPONSE

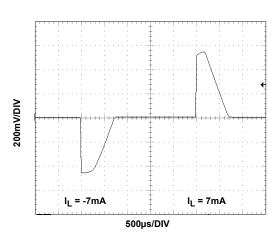


FIGURE 25. LOAD TRANSIENT RESPONSE

Typical Performance Characteristic Curves, V_{OUT} = 1.20V_(Continued)

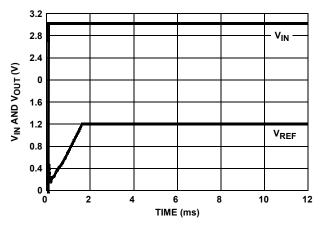


FIGURE 26. TURN-ON TIME (+25°C)

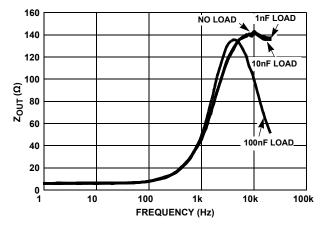


FIGURE 27. Z_{OUT} vs FREQUENCY

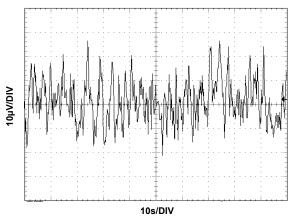


FIGURE 28. V_{OUT} NOISE

Typical Performance Characteristic Curves, $V_{OUT} = 1.25V$

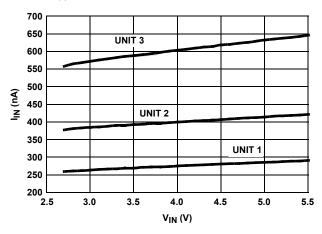


FIGURE 29. I_{IN} vs V_{IN} , 3 UNITS

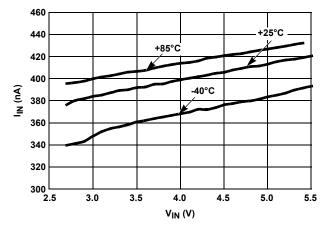


FIGURE 30. I_{IN} vs V_{IN} OVER-TEMPERATURE

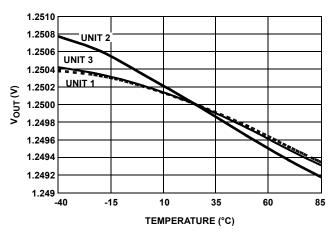


FIGURE 31. V_{OUT} vs TEMPERATURE NORMALIZED TO +25°C

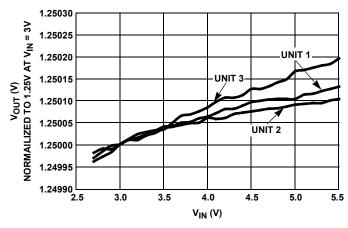


FIGURE 32. LINE REGULATION, 3 UNITS

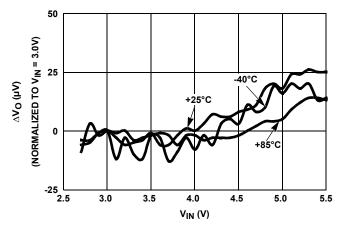


FIGURE 33. LINE REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, V_{OUT} = 1.25V_(Continued)

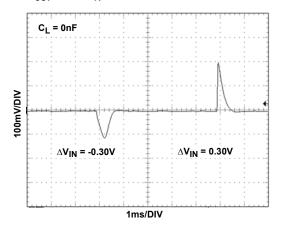


FIGURE 34. LINE TRANSIENT RESPONSE

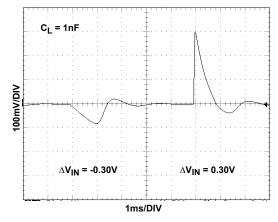


FIGURE 35. LINE TRANSIENT RESPONSE, WITH CAPACITIVE LOAD

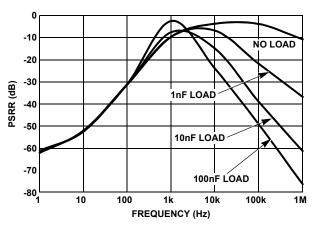


FIGURE 36. PSRR vs CAPACITIVE LOAD

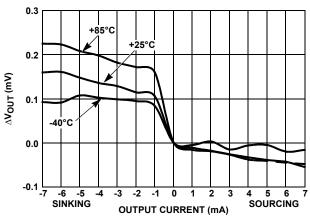


FIGURE 37. LOAD REGULATION

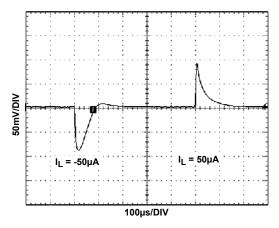


FIGURE 38. LOAD TRANSIENT RESPONSE

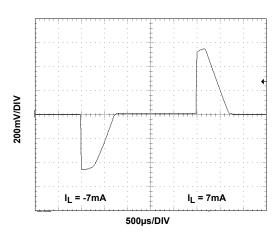


FIGURE 39. LOAD TRANSIENT RESPONSE

Typical Performance Characteristic Curves, V_{OUT} = 1.25V_(Continued)

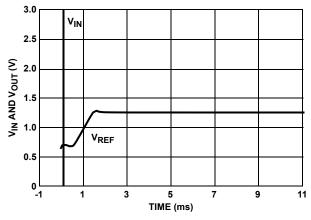


FIGURE 40. TURN-ON TIME (+25°C)

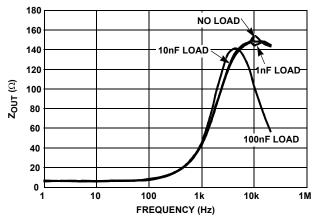


FIGURE 41. Z_{OUT} vs FREQUENCY

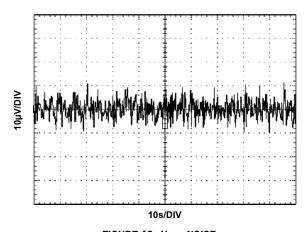


FIGURE 42. V_{OUT} NOISE

Typical Performance Curves, V_{OUT} = 1.8V

 V_{IN} = 3.0V, I_{OUT} = 0mA, T_A = +25 °C unless otherwise specified

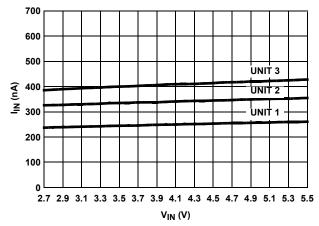


FIGURE 43. I_{IN} vs V_{IN} , 3 UNITS

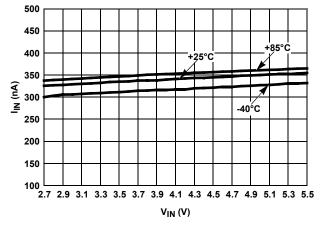


FIGURE 44. I_{IN} vs V_{IN} OVER-TEMPERATURE

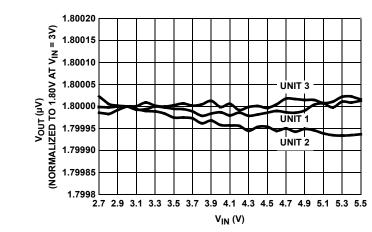


FIGURE 45. LINE REGULATION (3 REPRESENTATIVE UNITS)

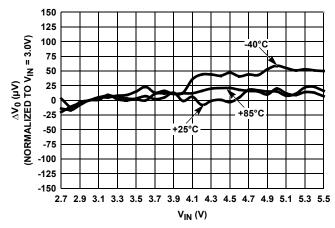


FIGURE 46. LINE REGULATION OVER-TEMPERATURE

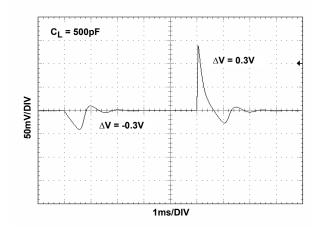


FIGURE 47. LINE TRANSIENT RESPONSE, WITH CAPACITIVE LOAD

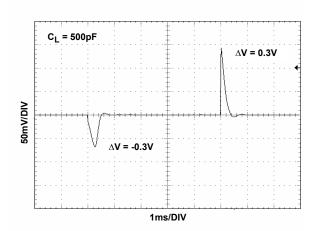


FIGURE 48. LINE TRANSIENT RESPONSE

Typical Performance Curves, V_{OUT} = 1.8V_(Continued)

 V_{IN} = 3.0V, I_{OUT} = 0mA, T_A = +25°C unless otherwise specified

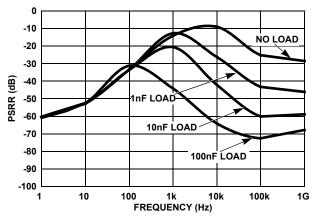


FIGURE 49. PSRR vs CAPACITIVE LOAD

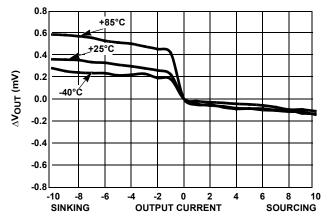


FIGURE 50. LOAD REGULATION OVER-TEMPERATURE

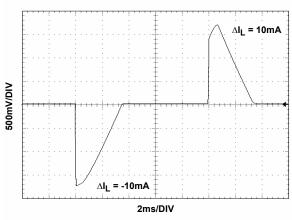


FIGURE 51. LOAD TRANSIENT RESPONSE

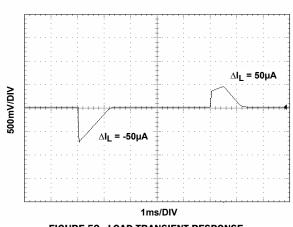


FIGURE 52. LOAD TRANSIENT RESPONSE

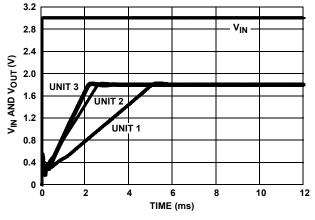


FIGURE 53. TURN-ON TIME (+25°C)

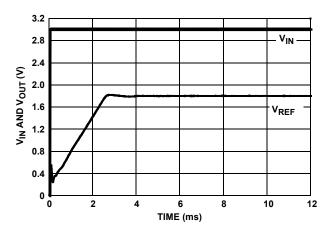


FIGURE 54. TURN-ON TIME (+25 $^{\circ}$ C)

Typical Performance Curves, $V_{OUT} = 1.8V_{(Continued)}$

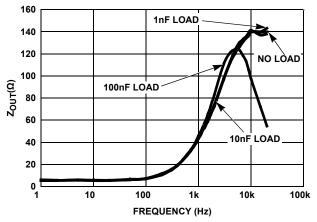


FIGURE 55. Z_{OUT} vs FREQUENCY

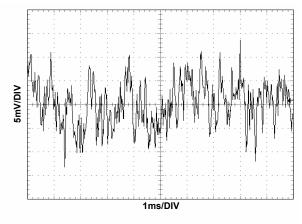


FIGURE 56. V_{OUT} NOISE

Typical Performance Curves, V_{OUT} = 2.048V

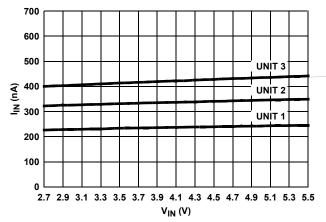


FIGURE 57. I_{IN} vs V_{IN} (3 REPRESENTATIVE UNITS)

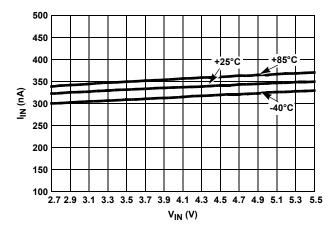


FIGURE 58. I_{IN} vs V_{IN} OVER-TEMPERATURE

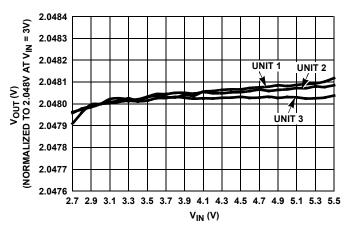


FIGURE 59. LINE REGULATION (3 REPRESENTATIVE UNITS)

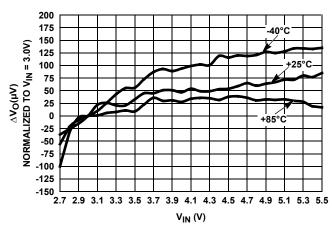


FIGURE 60. LINE REGULATION OVER-TEMPERATURE

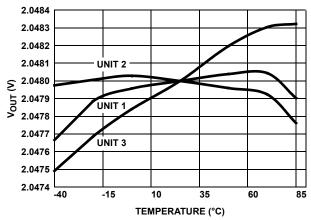
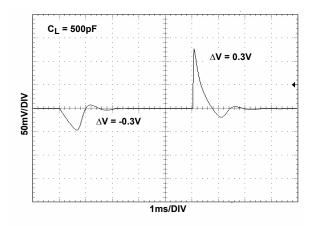


FIGURE 61. V_{OUT} vs TEMPERATURE NORMALIZED to +25°C

Typical Performance Curves, V_{OUT} = 2.048V_(Continued)



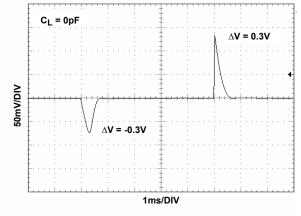
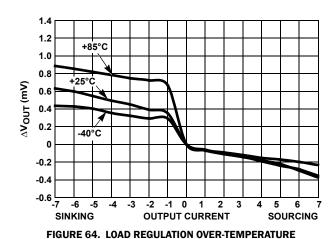


FIGURE 62. LINE TRANSIENT RESPONSE, WITH CAPACITIVE LOAD

FIGURE 63. LINE TRANSIENT RESPONSE



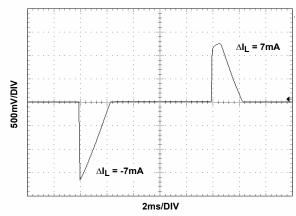


FIGURE 65. LOAD TRANSIENT RESPONSE

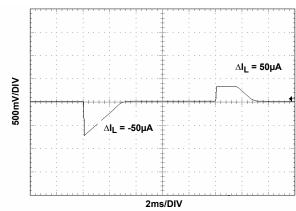
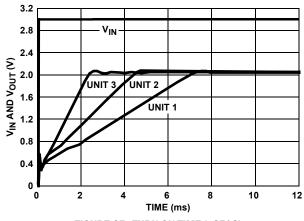


FIGURE 66. LOAD TRANSIENT RESPONSE

Typical Performance Curves, V_{OUT} = 2.048V_(Continued)

 V_{IN} = 3.0V, I_{OUT} = 0mA, T_A = +25 °C unless otherwise specified



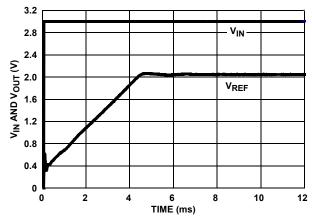


FIGURE 67. TURN-ON TIME (+25°C)

FIGURE 68. TURN-ON TIME (+25°C)

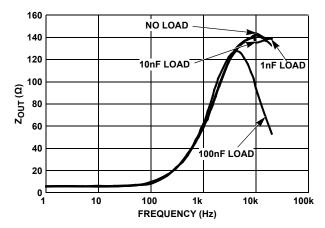


FIGURE 69. Z_{OUT} vs FREQUENCY

Typical Performance Characteristic Curves, $V_{OUT} = 2.50V$

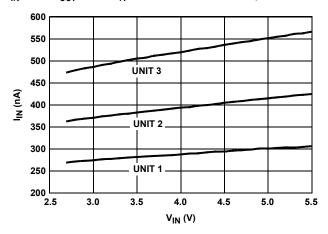


FIGURE 70. I_{IN} vs V_{IN} , 3 UNITS

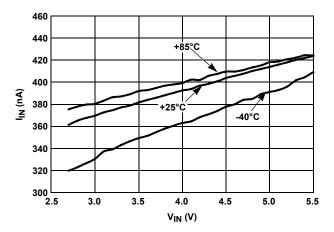


FIGURE 71. I_{IN} vs V_{IN} OVER-TEMPERATURE

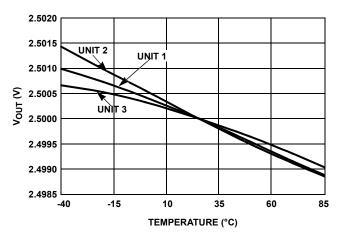


FIGURE 72. V_{OUT} vs temperature normalized to +25 °C

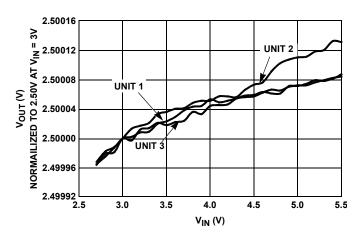


FIGURE 73. LINE REGULATION, 3 UNITS

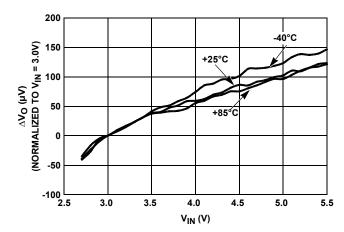


FIGURE 74. LINE REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, $V_{OUT} = 2.50V_{(Continued)}$

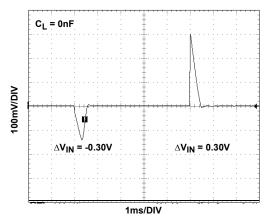


FIGURE 75. LINE TRANSIENT RESPONSE

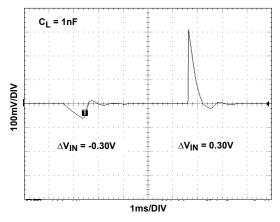


FIGURE 76. LINE TRANSIENT RESPONSE

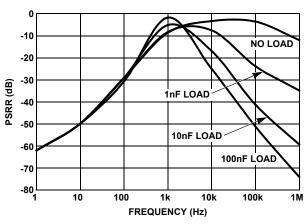


FIGURE 77. PSRR vs CAPACITIVE LOAD

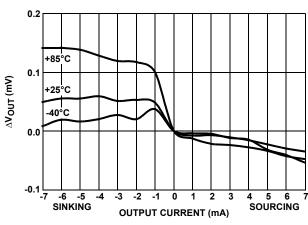


FIGURE 78. LOAD REGULATION OVER-TEMPERATURE

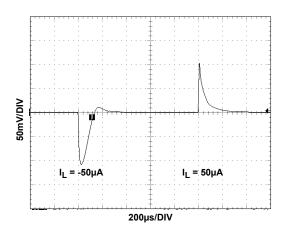


FIGURE 79. LOAD TRANSIENT RESPONSE

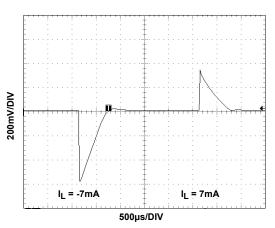


FIGURE 80. LOAD TRANSIENT RESPONSE

Typical Performance Characteristic Curves, V_{OUT} = 2.50V_(Continued)

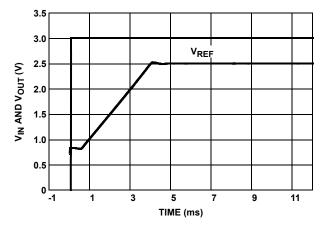


FIGURE 81. TURN-ON TIME (+25°C)

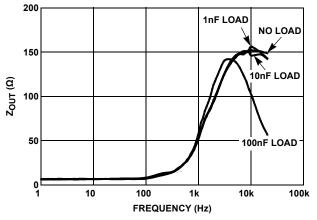
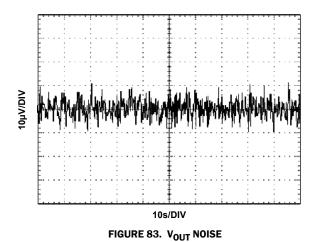
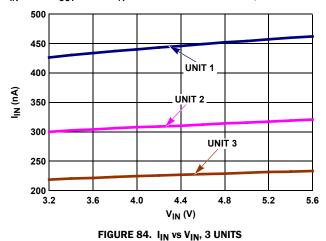


FIGURE 82. Z_{OUT} vs FREQUENCY



Typical Performance Characteristic Curves, $V_{OUT} = 3.0V$



350 335 320 +85°C In (nA) 305 290 275 -40°C 260 3.6 4.0 4.4 4.8 5.2 5.6 V_{IN} (V)

FIGURE 85. I_{IN} vs V_{IN} OVER-TEMPERATURE

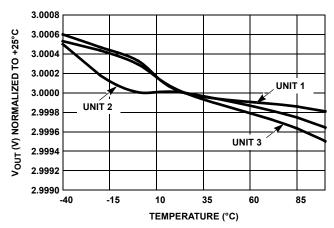


FIGURE 86. V_{OUT} vs TEMPERATURE NORMALIZED TO +25°C

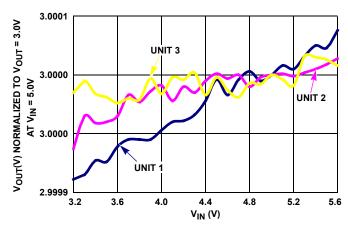


FIGURE 87. LINE REGULATION (3 REPRESENTATIVE UNITS)

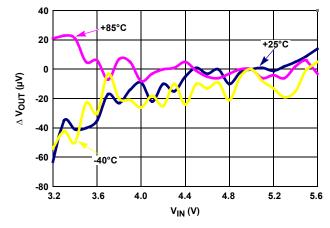


FIGURE 88. LINE REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, V_{OUT} = 3.0V_(Continued)

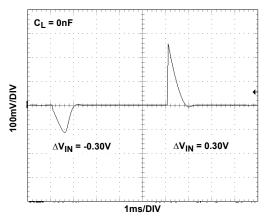


FIGURE 89. LINE TRANSIENT RESPONSE

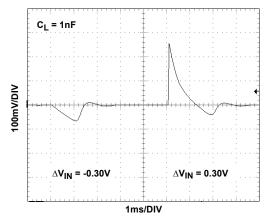


FIGURE 90. LINE TRANSIENT RESPONSE

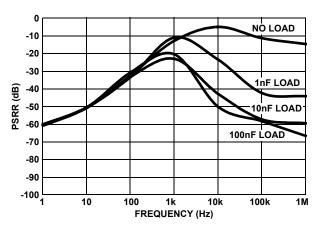


FIGURE 91. PSRR vs CAPACITIVE LOAD

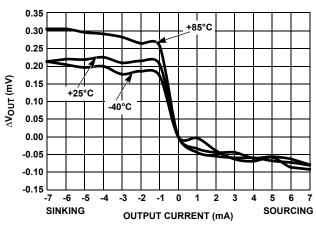


FIGURE 92. LOAD REGULATION OVER-TEMPERATURE

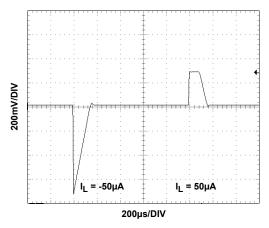


FIGURE 93. LOAD TRANSIENT RESPONSE

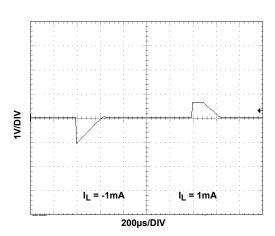


FIGURE 94. LOAD TRANSIENT RESPONSE

Typical Performance Characteristic Curves, V_{OUT} = 3.0V_(Continued)

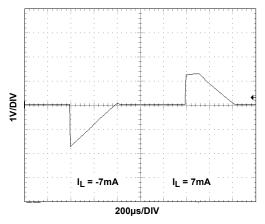


FIGURE 95. LOAD TRANSIENT RESPONSE

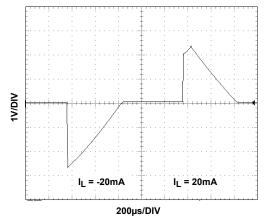


FIGURE 96. LOAD TRANSIENT RESPONSE

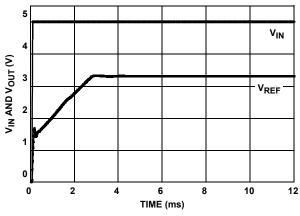


FIGURE 97. TURN-ON TIME (+25°C)

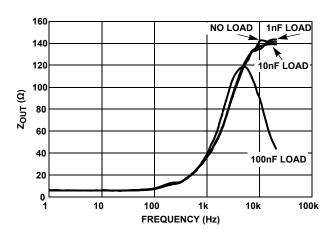


FIGURE 98. Z_{OUT} vs FREQUENCY

Typical Performance Characteristic Curves, $V_{OUT} = 3.3V$

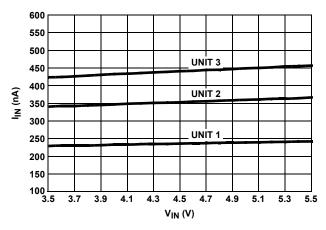


FIGURE 99. I_{IN} vs V_{IN}, 3 UNITS

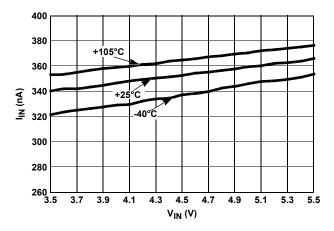


FIGURE 100. I_{IN} vs V_{IN} OVER-TEMPERATURE

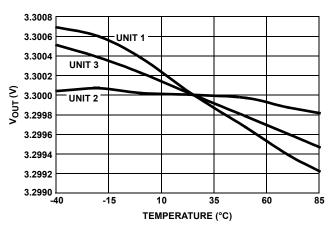


FIGURE 101. V_{OUT} vs temperature normalized to +25°C

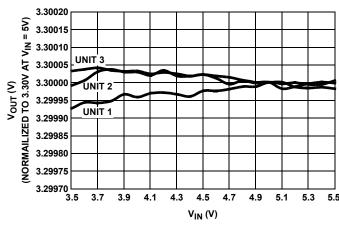


FIGURE 102. LINE REGULATION, 3 UNITS

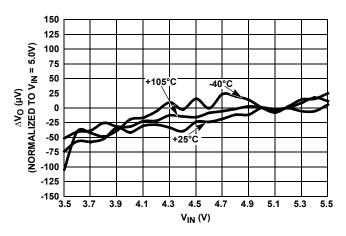


FIGURE 103. LINE REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, V_{OUT} = 3.3V_(Contlnued)

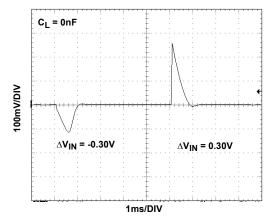


FIGURE 104. LINE TRANSIENT RESPONSE

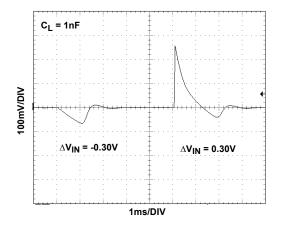


FIGURE 105. LINE TRANSIENT RESPONSE

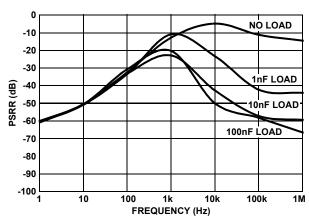
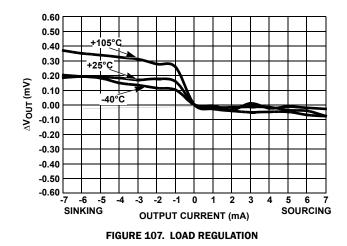


FIGURE 106. PSRR vs CAPACITIVE LOAD



1.00 +105°C 0.80 0.60 0.40 ∆VouT (mV) 0.20 0.00 -0.20 -0.40 -0.60 -0.80 -1.00 -20 -18 -16 -14 -12 -10 -8 -6 -4 -2 0 8 10 12 14 16 18 20 **SINKING** SOURCING **OUTPUT CURRENT (mA)**

FIGURE 108. LOAD REGULATION OVER-TEMPERATURE

Typical Performance Characteristic Curves, V_{OUT} = 3.3V_(Continued)

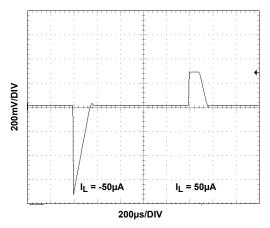


FIGURE 109. LOAD TRANSIENT RESPONSE

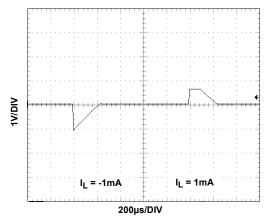


FIGURE 110. LOAD TRANSIENT RESPONSE

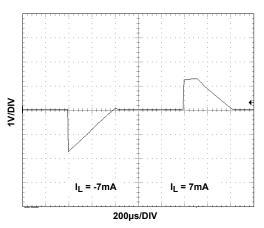


FIGURE 111. LOAD TRANSIENT RESPONSE

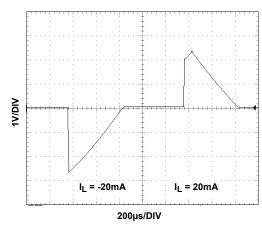


FIGURE 112. LOAD TRANSIENT RESPONSE

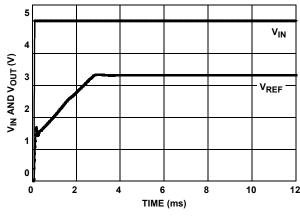


FIGURE 113. TURN-ON TIME (+25 $^{\circ}$ C)

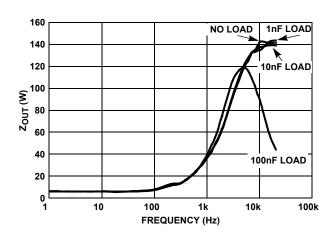


FIGURE 114. Z_{OUT} vs FREQUENCY

High Current Application

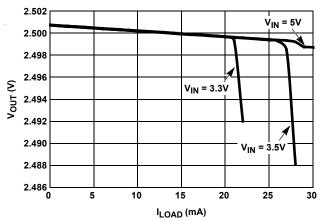


FIGURE 115. DIFFERENT VIN AT ROOM TEMPERATURE

Applications Information

FGA Technology

The ISL60002 series of voltage references use the floating gate technology to create references with very low drift and supply current. Essentially, the charge stored on a floating gate cell is set precisely in manufacturing. The reference voltage output itself is a buffered version of the floating gate voltage. The resulting reference device has excellent characteristics which are unique in the industry: very low temperature drift, high initial accuracy, and almost zero supply current. Also, the reference voltage itself is not limited by voltage bandgaps or zener settings, so a wide range of reference voltages can be programmed (standard voltage settings are provided, but customer-specific voltages are available).

The process used for these reference devices is a floating gate CMOS process, and the amplifier circuitry uses CMOS transistors for amplifier and output transistor circuitry. While providing excellent accuracy, there are limitations in output noise level and load regulation due to the MOS device characteristics. These limitations are addressed with circuit techniques discussed in other sections.

Nanopower Operation

Reference devices achieve their highest accuracy when powered up continuously, and after initial stabilization has taken place. This drift can be eliminated by leaving the power on continuously.

The ISL60002 is the first high precision voltage reference with ultra low power consumption that makes it possible to leave power on continuously in battery operated circuits. The ISL60002 consumes extremely low supply current due to the proprietary FGA technology. Supply current at room temperature is typically 350nA, which is 1 to 2 orders of magnitude lower than competitive devices. Application circuits using battery power will benefit greatly from having an accurate, stable reference, which essentially presents no load to the battery.

In particular, battery powered data converter circuits that would normally require the entire circuit to be disabled when not in use

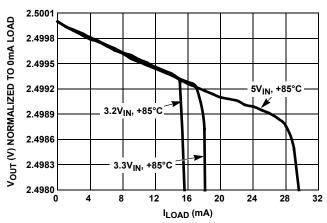


FIGURE 116. DIFFERENT VIN AT HIGH TEMPERATURE

can remain powered up between conversions as shown in Figure 117. Data acquisition circuits providing 12 to 24 bits of accuracy can operate with the reference device continuously biased with no power penalty, providing the highest accuracy and lowest possible long term drift.

Other reference devices consuming higher supply currents will need to be disabled in between conversions to conserve battery capacity. Absolute accuracy will suffer as the device is biased and requires time to settle to its final value, or, may not actually settle to a final value as power on time may be short.

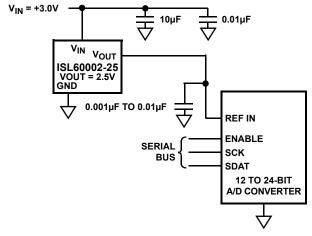


FIGURE 117.

Board Mounting Considerations

For applications requiring the highest accuracy, board mounting location should be reviewed. Placing the device in areas subject to slight twisting can cause degradation of the accuracy of the reference voltage due to die stresses. It is normally best to place the device near the edge of a board, or the shortest side, as the axis of bending is most limited at that location. Obviously mounting the device on flexprint or extremely thin PC material will likewise cause loss of reference accuracy.

Board Assembly Considerations

FGA references provide high accuracy and low temperature drift but some PC board assembly precautions are necessary. Normal Output voltage shifts of 100µV to 1mV can be expected with Pb-free reflow profiles. Precautions should be taken to avoid excessive heat or extended exposure to high reflow temperatures, which may reduce device initial accuracy.

Post-assembly x-ray inspection may also lead to permanent changes in device output voltage and should be minimized or avoided. If x-ray inspection is required, it is advisable to monitor the reference output voltage to verify excessive shift has not occurred. If large amounts of shift are observed, it is best to add an X-ray shield consisting of thin zinc (300µm) sheeting to allow clear imaging, yet block x-ray energy that affects the FGA reference.

Special Applications Considerations

In addition to post-assembly examination, there are also other X-ray sources that may affect the FGA reference long term accuracy. Airport screening machines contain X-rays and will have a cumulative effect on the voltage reference output accuracy. Carry-on luggage screening uses low level X-rays and is not a major source of output voltage shift, however, if a product is expected to pass through that type of screening over 100 times, it may need to consider shielding with copper or aluminum. Checked luggage X-rays are higher intensity and can cause output voltage shift in much fewer passes, thus devices expected to go through those machines should definitely consider shielding. Note that just two layers of 1/2 ounce copper planes will reduce the received dose by over 90%. The leadframe for the device which is on the bottom also provides similar shielding.

If a device is expected to pass through luggage X-ray machines numerous times, it is advised to mount a 2-layer (minimum) PC board on the top, and along with a ground plane underneath will effectively shield it from 50 to 100 passes through the machine. Since these machines vary in X-ray dose delivered, it is difficult to produce an accurate maximum pass recommendation.

Noise Performance and Reduction

The output noise voltage in a 0.1Hz to 10Hz bandwidth is typically $30\mu V_{P\!-\!P\!\cdot}$ This is shown in the plot in the Typical Performance Curves. The noise measurement is made with a bandpass filter made of a 1 pole high-pass filter with a corner frequency at 0.1Hz and a 2-pole low-pass filter with a corner frequency at 12.6Hz to create a filter with a 9.9Hz bandwidth. Noise in the 10kHz to 1MHz bandwidth is approximately 400μV_{P-P} with no capacitance on the output, as shown in Figure 118. These noise measurements are made with a 2 decade bandpass filter made of a 1 pole high-pass filter with a corner frequency at 1/10 of the center frequency and 1-pole low-pass filter with a corner frequency at 10 times the center frequency. Figure 118 also shows the noise in the 10kHz to 1MHz band can be reduced to about 50µV_{P-P} using a 0.001µF capacitor on the output. Noise in the 1kHz to 100kHz band can be further reduced using a 0.1µF capacitor on the output, but noise in the 1Hz to 100Hz band increases due to instability of the very low power amplifier with a 0.1µF capacitance load. For load capacitances above 0.001µF the noise reduction network shown in Figure 119 is recommended. This network reduces noise

significantly over the full bandwidth. As shown in Figure 118, noise is reduced to less than $40\mu V_{\text{P-P}}$ from 1Hz to 1MHz using this network with a $0.01\mu F$ capacitor and a $2k\Omega$ resistor in series with a 10µF capacitor.

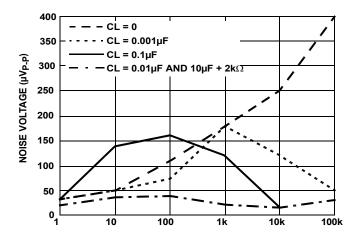


FIGURE 118. NOISE REDUCTION

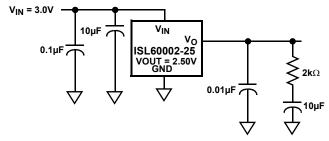
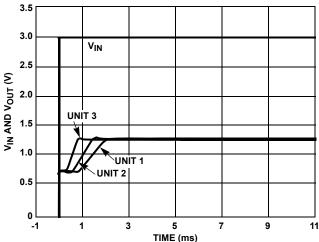


FIGURE 119. NOISE REDUCTION NETWORK

Turn-On Time

The ISL60002 devices have ultra-low supply current and thus the time to bias up internal circuitry to final values will be longer than with higher power references. Normal turn-on time is typically 7ms. This is shown in Figure 120. Since devices can vary in supply current down to >300nA, turn-on time can last up to about 12ms. Care should be taken in system design to include this delay before measurements or conversions are started.



3.5 3.0 2.5 2.0 V_{IN} UNIT 3 UNIT 1 UNIT 2 UNIT 2

FIGURE 120. TURN-ON TIME

TIME (ms)

Typical Application Circuits

0

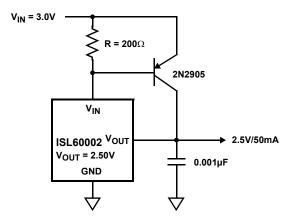


FIGURE 121. PRECISION 2.5V 50mA REFERENCE

Temperature Coefficient

The limits stated for temperature coefficient (tempco) are governed by the method of measurement. The overwhelming standard for specifying the temperature drift of a reference is to measure the reference voltage at two temperatures, take the total variation, $(V_{HIGH} - V_{LOW})$, and divide by the temperature extremes of measurement ($T_{HIGH} - T_{LOW}$). The result is divided by the nominal reference voltage (at T = +25 °C) and multiplied by 10^6 to yield ppm/ °C. This is the "Box" method for specifying temperature coefficient.

Typical Application Circuits (Continued)

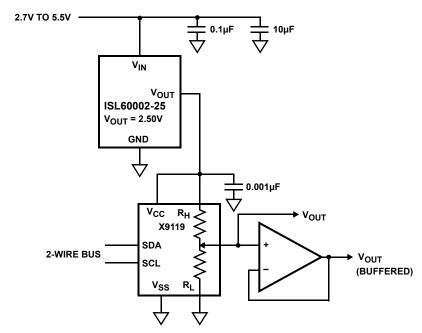


FIGURE 122. 2.5V FULL SCALE LOW-DRIFT 10-BIT ADJUSTABLE VOLTAGE SOURCE

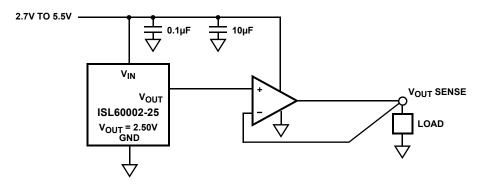


FIGURE 123. KELVIN SENSED LOAD

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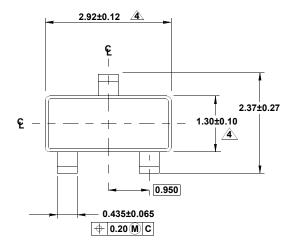
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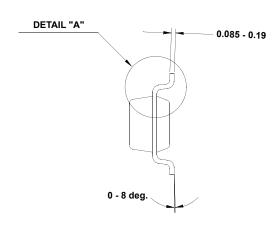
Package Outline Drawing P3.064

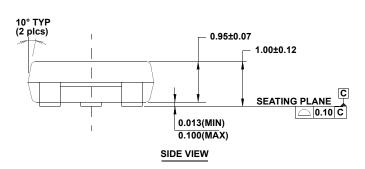
3 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE (SOT23-3)

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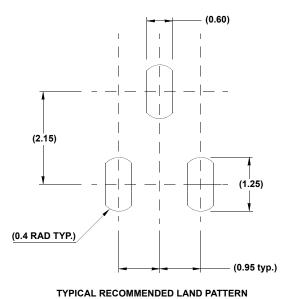


TOP VIEW





0.25
GAUGE PLANE
SEATING PLANE
0.38±0.10 Ŝ



NOTES:

- Dimensions are in millimeters.
 Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to AMSEY14.5m-1994.
- 3. Reference JEDEC TO-236.
- Dimension does not include interlead flash or protrusions.
 Interlead flash or protrusions shall not exceed 0.25mm per side.
- 5. Footlength is measured at reference to gauge plane.